

BC817-25QCZ Datasheet



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DiGi Electronics Part Number BC817-25QCZ-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC817-25QCZ

Description TRANS NPN 45V 0.5A DFN1412D-3

Detailed Description Bipolar (BJT) Transistor NPN 45 V 500 mA 100MHz 3

80 mW Surface Mount, Wettable Flank DFN1412D-3



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC817-25QCZ	Nexperia USA Inc.
Series:	Product Status:
BC817QC	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
45 V	700mV @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	160 @ 100mA, 1V
Power - Max:	Frequency - Transition:
380 mW	100MHz
Operating Temperature:	Mounting Type:
150°C (TJ)	Surface Mount, Wettable Flank
Package / Case:	Supplier Device Package:
3-XDFN Exposed Pad	DFN1412D-3
Base Product Number:	
BC817	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	3 (168 Hours)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	

1. General description

NPN general-purpose transistor in an ultra small DFN1412D-3 (SOT8009) leadless Surface-Mounted Device (SMD) plastic package with side-wettable flanks.

Table 1. Product overview

Type number	Package	PNP complement		
	Name	JEDEC	Version	
BC817-16QC	DFN1412D-3	MO-340CA	SOT8009	BC807-16QC
BC817-25QC				BC807-25QC
BC817-40QC				BC807-40QC

2. Features and benefits

- · High power dissipation capability
- High current
- Three current gain selections
- · Suitable for Automatic Optical Inspection (AOI) of solder joint
- · Smaller footprint compared to conventional leaded SMD packages
- Low package height of 0.5 mm
- AEC-Q101 qualified

3. Applications

- · General-purpose switching and amplification
- Space restricted applications

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-	45	V
I _C	collector current	T _{amb} = 25 °C		-	-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-	1	А
h _{FE}	DC current gain						
	BC817-16QC	V _{CE} = 1 V; I _C = 100 mA T _{amb} = 25 °C	[1]	100	-	250	
	BC817-25QC		[1]	160	-	400	
	BC817-40QC		[1]	250	-	600	

[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base		C
2	E	emitter		B—
3	С	collector	3	E sym021
			Bottom view DFN1412D-3 (SOT8009)	

6. Ordering information

Table 4. Ordering information

Table 4. Ordering information							
Type number	Package	ackage					
	Name	Description	Version				
BC817-16QC	DFN1412D-3	DFN1412D-3: plastic thermal enhanced ultra thin small outline	SOT8009				
BC817-25QC		package; no leads; 3 terminals; body: 1.4 x 1.2 x 0.5 mm	(MO-340CA)				
BC817-40QC							

7. Marking

Table 5. Marking

Type number	Marking code
BC817-16QC	9M
BC817-25QC	9N
BC817-40QC	9P

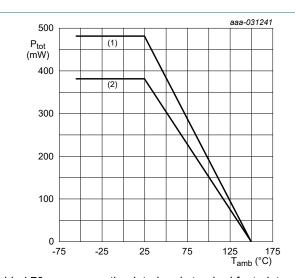
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter; T _{amb} = 25 °C	open emitter; T _{amb} = 25 °C		50	V
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	45	V
V _{EBO}	emitter-base voltage	open collector; T _{amb} = 25 °C		-	5	V
I _C	collector current	T _{amb} = 25 °C	T _{amb} = 25 °C			mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb}	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C			Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms; T _{amb}	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C			mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	380	mW
			[2]	-	480	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided 70 µm copper, tin-plated and standard footprint.



- (1) FR4 PCB; single-sided 70 μm copper, tin-plated and standard footprint
- (2) FR4 PCB; single-sided 35 µm copper, tin-plated and standard footprint

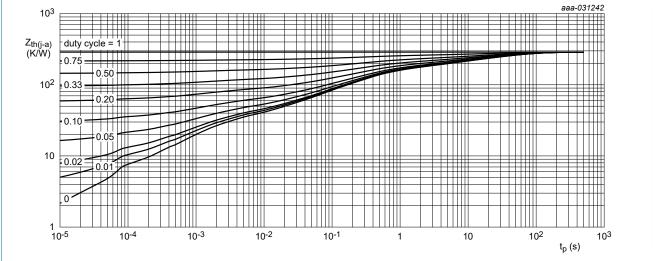
Fig. 1. Power derating curves for SOT8009

9. Thermal characteristics

Table 7. Thermal characteristics

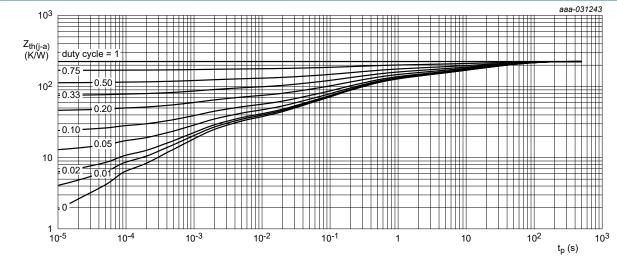
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air;	[1]	-	-	329	K/W
		T _{amb} = 25 °C	[2]	-	-	261	K/W

- [1] Device mounted on an FR4 PCB, single-sided 35 µm copper, tin-plated and standard footprint.



FR4 PCB, single-sided 35µm copper, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided 70µm copper, tin-plated and standard footprint

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

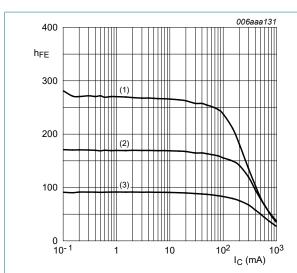
45 V, 500 mA NPN general-purpose transistors

10. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A; T _{amb} = 25 °C		50	-		V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	I _C = 10 mA; I _E = 0 A; T _{amb} = 25 °C		45	-		V
$V_{(BR)EBO}$	emitter-base breakdown voltage	I _E = 100 μA; I _C = 0 A; T _{amb} = 25 °C	I _E = 100 μA; I _C = 0 A; T _{amb} = 25 °C		-		V
I _{CBO}	collector-base	V _{CB} = 20 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
	cut-off current	V _{CB} = 20 V; I _E = 0 A; T _j = 150 °C		-	-	5	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
h _{FE}	DC current gain						'
	BC817-16QC	V _{CE} = 1 V; I _C = 100 mA; T _{amb} = 25 °C	[1]	100	-	250	
	BC817-25QC	V _{CE} = 1 V; I _C = 100 mA; T _{amb} = 25 °C	[1]	160	-	400	
	BC817-40QC	V _{CE} = 1 V; I _C = 100 mA; T _{amb} = 25 °C	[1]	250	-	600	
		V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C		40	-	-	
V _{CEsat}	collector-emitter saturation voltage	I _C = 500 mA; I _B = 50 mA; T _{amb} = 25 °C	[1]	-	-	700	mV
V_{BE}	base-emitter voltage	V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	-	-	1.2	V
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz; T _{amb} = 25 °C		100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$		-	3	-	pF

^[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$

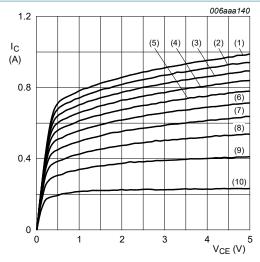


$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. BC817-16QC: DC current gain as a function of collector current; typical values



(1)
$$I_B = 16.0 \text{ mA}$$

(2)
$$I_B = 14.4 \text{ mA}$$

$$(3) I_B = 12.8 \text{ mA}$$

(4)
$$I_B = 11.2 \text{ mA}$$

$$(5) I_B = 9.6 \text{ mA}$$

(6)
$$I_B = 8.0 \text{ mA}$$

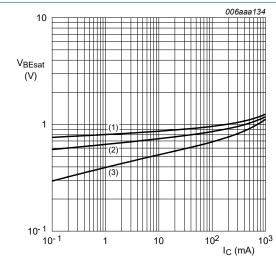
(7)
$$I_B = 6.4 \text{ mA}$$

(8)
$$I_B = 4.8 \text{ mA}$$

(9)
$$I_B = 3.2 \text{ mA}$$

(10)
$$I_B = 1.6 \text{ mA}$$

Fig. 5. BC817-16QC: Collector current as a function of collector-emitter voltage; typical values

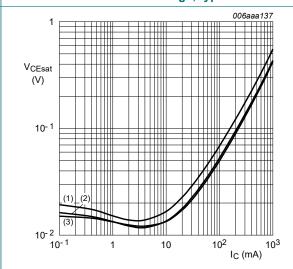


(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb}$$
 = 25 °C

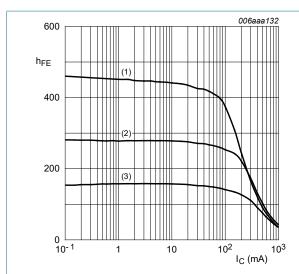
(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 6. BC817-16QC: Base-emitter saturation voltage as a function of collector current; typical values



(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 7. BC817-16QC: Collector-emitter saturation voltage as a function of collector current; typical values

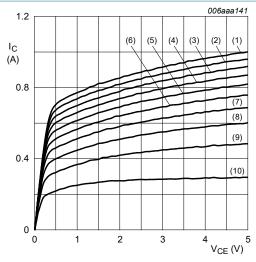


$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. BC817-25QC: DC current gain as a function of collector current; typical values



(1)
$$I_B = 13.0 \text{ mA}$$

(2)
$$I_B = 11.7 \text{ mA}$$

$$(3) I_B = 10.4 \text{ mA}$$

$$(4) I_B = 9.1 mA$$

$$(5) I_B = 7.8 \text{ mA}$$

(6)
$$I_B = 6.5 \text{ mA}$$

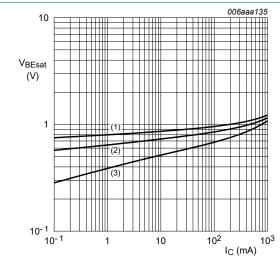
$$(7) I_B = 5.2 \text{ mA}$$

(8)
$$I_B = 3.9 \text{ mA}$$

(9)
$$I_B = 2.6 \text{ mA}$$

$$(10) I_B = 1.3 mA$$

Fig. 9. BC817-25QC: Collector current as a function of collector-emitter voltage; typical values

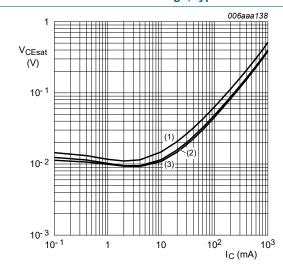


(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

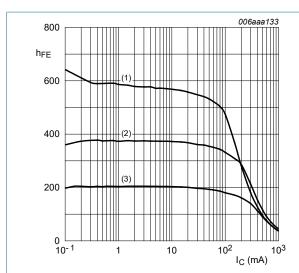
Fig. 10. BC817-25QC: Base-emitter saturation voltage as a function of collector current; typical values



(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 11. BC817-25QC: Collector-emitter saturation voltage as a function of collector current; typical values



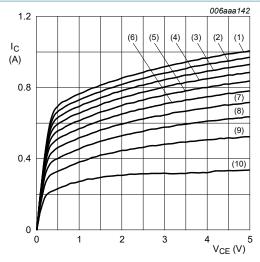
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 12. BC817-40QC: DC current gain as a function of collector current; typical values



$$(1) I_B = 12.0 \text{ mA}$$

$$(2) I_B = 10.8 \text{ mA}$$

(3)
$$I_B = 9.6 \text{ mA}$$

$$(4) I_B = 8.4 \text{ mA}$$

$$(5) I_B = 7.2 \text{ mA}$$

(6)
$$I_B = 6.0 \text{ mA}$$

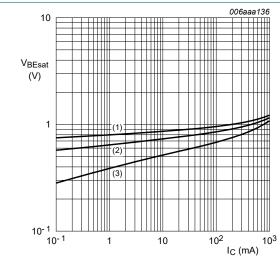
(7)
$$I_B = 4.8 \text{ mA}$$

(8)
$$I_B = 3.6 \text{ mA}$$

(9)
$$I_B = 2.4 \text{ mA}$$

(10)
$$I_B = 1.2 \text{ mA}$$

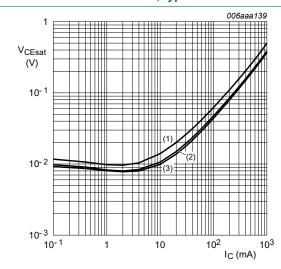
Fig. 13. BC817-40QC: Transition frequency as a function of collector current; typical values



(1)
$$T_{amb} = -55$$
 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 14. BC817-40QC: Base-emitter saturation voltage as a function of collector current; typical values



(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 15. BC817-40QC: Collector-emitter saturation voltage as a function of collector current; typical values

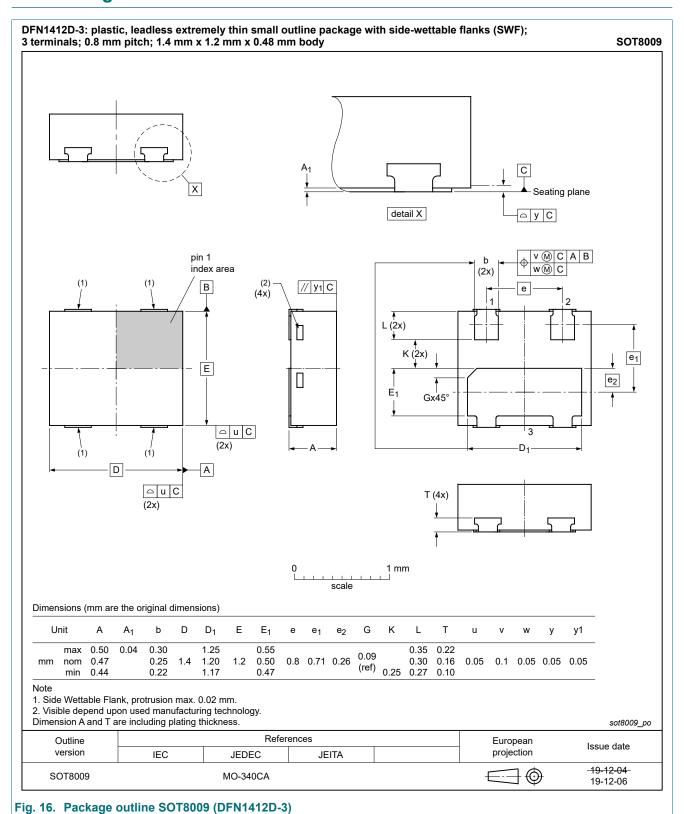
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11. Test information

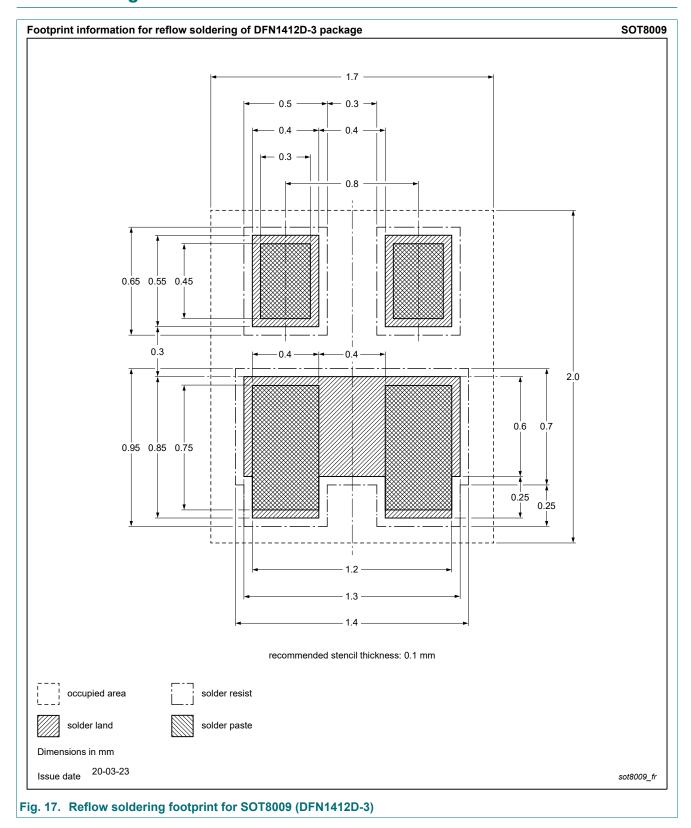
11.1. Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



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14. Revision history

Table 9. Revision history

Table of Novicion motory					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
BC817QC_SER v.2	20201028	Product data sheet	-	BC817QC_SER v.1	
Modifications:	Thermal characteristics: R _{th(j-sp)} removed				
BC817QC_SER v.1	20200512	Product data sheet	-	-	

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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